

February 2012

FJB5555 NPN Silicon Transistor

Features

- High Voltage Switch Mode Application
- Fast Speed Switching
- Wide Safe Operating Area
- Suitable for Electronic Ballast Application



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units	
BV _{CBO}	Collector-Base Voltage	1050	V	
BV _{CEO}	Collector-Emitter Voltage	400	V	
BV _{EBO}	Emitter-Base Voltage	14	V	
I _C	Collector Current (DC)	5	Α	
I _{CP}	Collector Current (Pulse)	10	Α	
I _B	Base Current (DC)	2	Α	
I _{BP}	Collector Current (Pulse)	4	Α	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Junction Temperature Range	- 55 to 150	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter		Value	Units	
P _D	Total Device Dissipation	$T_a = 25$ °C $T_c = 25$ °C	1.6 100	W W	
$R_{\theta ja}$	Thermal Resistance, Junction to Ambient	77.75	°C/W		
$R_{ hetajc}$	Thermal Resistance, Junction to Case	1.25	°C/W		

^{*} Device mounted on minimum pad size

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
FJB5555TM	J5555	D2-PAK	Tape & Reel	

Electrical Characteristics* $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =500μA, I _E =0	1050			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5$ mA, $I_B=0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =500μA, I _C =0	14			V
h _{FE}	DC Current Gain	V _{CE} =5V, I _C =10mA	10			
		V_{CE} =3V, I_{C} =0.8A	20		40	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =1A, I _B =0.2A		0.17	0.5	V
		I _C =3.5A, I _B =1.0A			1.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =3.5A, I _B =1.0A			1.2	V
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz		45		pF
t _{ON}	Turn On Time	V _{CC} =125V, I _C =0.5A			1.0	μS
t _{STG}	Storage Time	I _{B1} =45mA, I _{B2} =-0.5A			1.2	μS
t _F	Fall Time	$R_L=250\Omega$		0.3		μS
t _{ON}	Turn On Time	V _{CC} =250V, I _C =2.5A			2.0	μS
t _{STG}	Storage Time	I _{B1} =0.5A, I _{B2} =-1.0A			2.5	μS
t _F	Fall Time	$R_L=100\Omega$			0.3	μS
EAS	Avalanche Energy	L=2mH	6			mJ

^{*} Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

Typical Characteristics

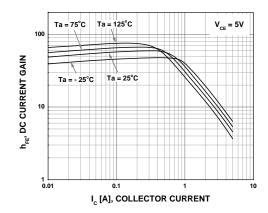


Figure 1. DC Current Gain

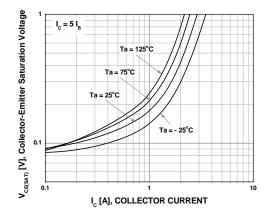


Figure 2. Saturation Voltage

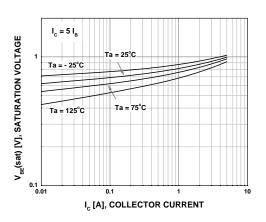


Figure 3. Saturation Voltage

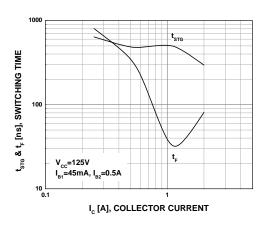


Figure 4. Resistive Load Switching

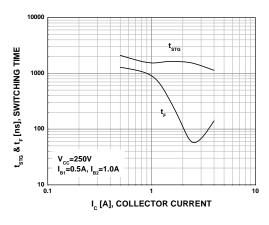


Figure 5. Resistive Load Switching

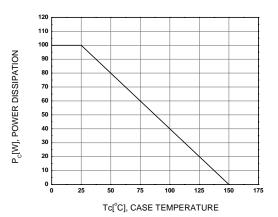


Figure 6. Power Derating

Typical Characteristics (Continued)

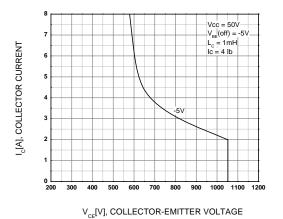
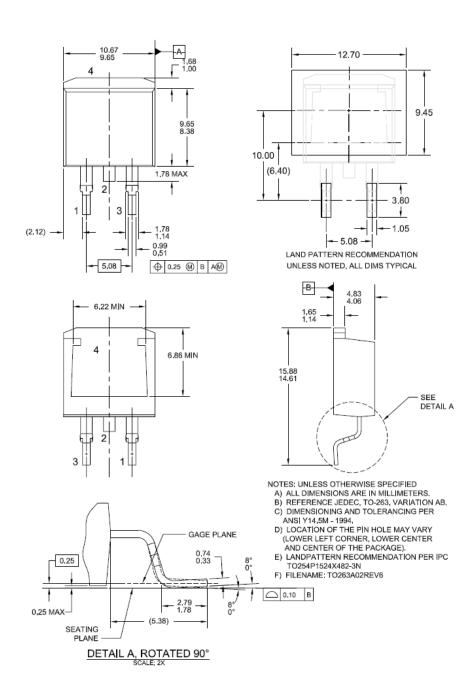


Figure 7. Reverse Bias Safe Operating

Physical Dimensions

D²-PAK



Dimensions in Millimeters



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Definition of Terms		
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